# NSN 5962-01-303-0779

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View Online at https://aerobasegroup.com/nsn/5962-01-303-0779

#### **Overall Length:**

1.280 inches

**Overall Height:** 

0.400 inches

# **Overall Width:**

0.390 inches

#### **Body Length:**

1.280 inches

#### **Body Width:**

0.310 inches

# **Body Height:**

0.160 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and electrostatic sensitive and programmed and ultraviolet erasable

#### Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Complementary-metal oxide-semiconductor logic

# Input Circuit Pattern:

15 input

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

7.0 volts power source

# Memory Device Type:

Prom

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

24 printed circuit

# Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

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